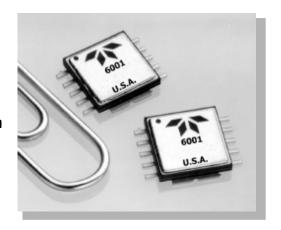
# 6001

# 5.150 to 5.300 GHz GaAs MMIC Hiperlan Band Power Amplifier

## **Features**

- ♦ +23 dBm Output Power @1 dB Gain Compression
- ♦ 23 dB Minimum Small Signal Gain
- ♦ 34dBm Third Order Intercept Point
- Surface Mount, Thermally Optimum Moly-Copper Package

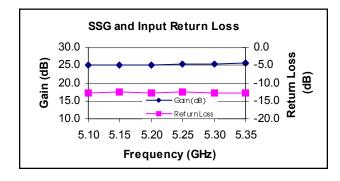


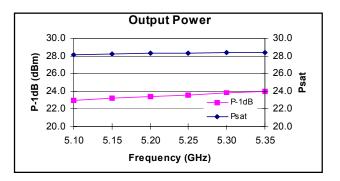
## **Product Description**

The 6001 GaAs MMIC power amplifier is designed to operate in the Hiperlan band of 5.150 to 5.300 GHz. It provides a minimum of 23 dB gain, a minimum of +23 dBm linear output power when measured at P-1 dB, and a minimum IP3 of 33dBm. It is housed in a thermally optimum copper-tungsten surface mount package and is capable of performing within typical commercial system operating temperature ranges.

**Electrical Specifications** (All Specifications at 25°C,  $V_d = +7.0V$ ,  $I_d = 600$  mA)

Symbol	Min	Max	Turning	11 14
		iviax	Typical	Units
F <sub>OP</sub>	5.15	5.30	-	GHz
S <sub>21</sub>	23	-	25.0	dB
S <sub>11</sub>	-	-	-10.0	dB
S <sub>12</sub>	-	-	52.0	dB
P <sub>-1dB</sub>	23	-	24.0	dBm
IP3	-	-	34.0	dBm
∆S <sub>21</sub>	-	-	-0.045	dB/°C
	F <sub>OP</sub> S <sub>21</sub> S <sub>11</sub> S <sub>12</sub> P <sub>-1dB</sub> IP3	F <sub>OP</sub> 5.15 S <sub>21</sub> 23 S <sub>11</sub> - S <sub>12</sub> - P <sub>-1dB</sub> 23 IP3 -	FOP     5.15     5.30       S21     23     -       S11     -     -       S12     -     -       P-1dB     23     -       IP3     -     -	FOP     5.15     5.30     -       S21     23     -     25.0       S11     -     -     -10.0       S12     -     -     52.0       P-1dB     23     -     24.0       IP3     -     34.0



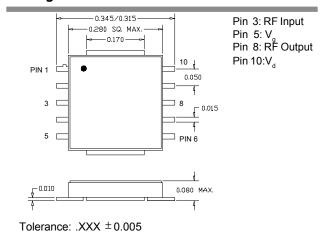




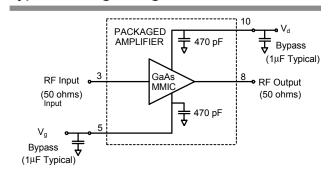
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# 5.150 to 5.300 GHz GaAs MMIC Power Amplifier for Hiperlan Applications

### Package Outline

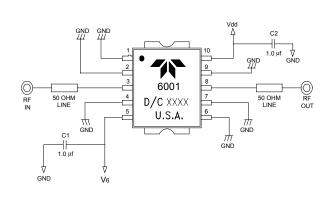


#### Typical Biasing Configuration

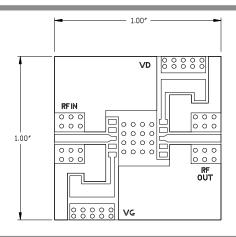


External Components Required: Bypass Capacitors: 1μ F, typical 50 Ohm microsrtip interface

#### **Evaluation Circuit**



#### **Evaluation Board**



#### Notes

- Dual bias supply required.
- 2. DC supply sequencing or protection circuitry not included. See Amplifier Biasing Procedure
- 3. A 360 pF DC supply line decoupling capacitor is included on both V<sub>a</sub> and V<sub>a</sub> lines. (See typical biasing configuration shown above).
- 4. The last fixture or circuit should incorporate additional bypass capacity (25ufd) on the drain and gate bias terminals to prevent oscillations caused by feedback signals.
- 5. Supply (drain and gate) wire/leads should be as short as possible.
- 6. Close placement of external components to the power amplifier is essential for stability purposes.
- 7. TET recommends the unit be soldered to DC and RF ground for best results.
- 8. Pin numbers indicated on outline drawing are for user information only. Units are not labeled with pin numbers.
- 9. MASK drawing for circuit board available on the Teledyne Wireless website at www.teledynewireless.com.

Teledyne reserves the right to make changes without further notice to any specification herein. "Typical" parameters can and do vary.



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